MSKSEMI 美森科













ESD

1/5

TSS

MOV

GDT

PIFD

ESD5311N-MS

Product specification





FEATURES

• Ultra Low Capacitance: 0.30pF(typ.)

Reverse Working Voltage: 5V

• IEC 61000-4-2 (ESD Air): ±20kV

IEC 61000-4-2 (ESD Contact): ±20kV

IEC 61000-4-5 (Lightning 8/20µs): 5A

APPLICATIONS

- Smart Phone and Tablet PC
- TV and Set Top Box
- Wearable Devices
- PDA

Reference News

PACKAGE OUTLINE	PIN CONFIGURATION	Marking
	1 2	5F
DFN1006		

Limiting Values(TA = 25 °C, unless otherwise specified)

Symbol	Parameter	Conditions	Min	Max	Unit
Vesd	IEC 61000-4-2; Contact Discharge Electrostatic Discharge Voltage		-	±20	kV
		IEC 61000-4-2; Air Discharge	-	±20	kV
P _{PP}	Peak Pulse Power	t _P = 8/20 μs	-	110	W
[РРМ	Rated Peak Pulse Current	t _P = 8/20 μs	-	5.0	Α
Та	Operating Temperature Range	-	-55	125	°C
Tstg	Storage Temperature Range	-	-55	150	°C



Electrical Characteristics(TA = 25 °C unless otherwise specified)

Symbol	Parameter	Conditions	Min	Тур.	Max	Unit
VRWM	Reverse Working Voltage	T _A = 25 °C	-	-	5.0	V
V _{BR}	Breakdown Voltage	I _R = 1mA; T _A = 25 °C	6.0	8.5	9.5	>
I _R	Reverse Leakage Current	V _{RWM} = 5V; T _A = 25 °C	-	-	0.1	μΑ
Vc Cla	Clamping Voltage	I _{PP} = 1A, t _P =8/20µs	-	-	10	٧
		IPP=5.0A, tP=8/20µs	-	-	22	V
Cı	Junction Capacitance	V _R = 0V, f = 1 MHz	-	0.30	0.40	pF

Typical Characteristics

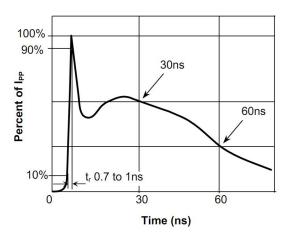


Fig.1 Pulse Waveform-ESD (IEC61000-4-2)

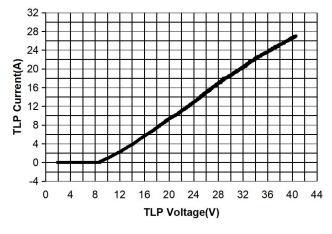
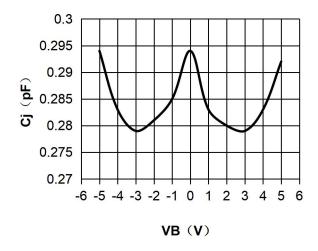
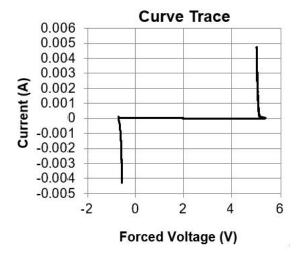


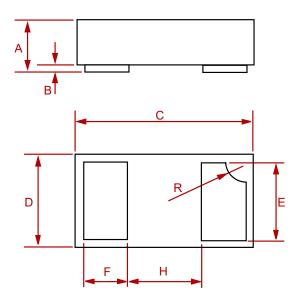
Fig.2 Transmission Line Pulse (TLP)





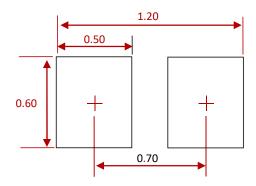


PACKAGEMECHANICALDATA



Dim	Inches		Millimeters		
Dim	MIN	MAX	MIN	MAX	
А	0.0125	0.02	0.32	0.52	
В	0.000	0.002	0.00	0.05	
С	0.037	0.043	0.95	1.080	
D	0.022	0.027	0.55	0.680	
E	0.016	0.024	0.40	0.60	
F	0.008	0.012	0.20	0.30	
Н	0.015Typ.		0.40Тур.		
R	0.001	0.005	0.05	0.15	

Suggested Pad Layout



NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

REELSPECIFICATION

P/N	PKG	QTY
ESD5311N-MS	DFN1006	10000



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